

# BDX33B, BDX33C (NPN) BDX34B, BDX34C (PNP)



ON Semiconductor®

<http://onsemi.com>

## Darlington Complementary Silicon Power Transistors

These devices are designed for general purpose and low speed switching applications.

### Features

- High DC Current Gain –  $h_{FE} = 2500$  (typ.) at  $I_C = 4.0$
- Collector–Emitter Sustaining Voltage at 100 mAdc  
 $V_{CEO(sus)} = 80$  Vdc (min) – BDX33B, BDX334B  
 $= 100$  Vdc (min) – BDX33C, BDX334C
- Low Collector–Emitter Saturation Voltage  
 $V_{CE(sat)} = 2.5$  Vdc (max) at  $I_C = 3.0$  Adc  
– BDX33B, 33C/34B, 34C
- Monolithic Construction with Build–In Base–Emitter Shunt Resistors
- Pb–Free Packages are Available\*

### MAXIMUM RATINGS

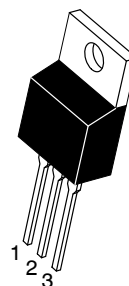
Rating	Symbol	Value	Unit
Collector–Emitter Voltage BDX33B, BDX34B BDX33C, BDX34C	$V_{CEO}$	80 100	Vdc
Collector–Base Voltage BDX33B, BDX34B BDX33C, BDX34C	$V_{CB}$	80 100	Vdc
Emitter–Base Voltage	$V_{EB}$	5.0	Vdc
Collector Current – Continuous – Peak	$I_C$	10 15	A dc
Base Current	$I_B$	0.25	A dc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	70 0.56	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	–65 to +150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	1.78	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## DARLINGTON 10 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80–100 VOLTS, 65 WATTS



TO-220AB  
CASE 221A-09  
STYLE 1

### MARKING DIAGRAM



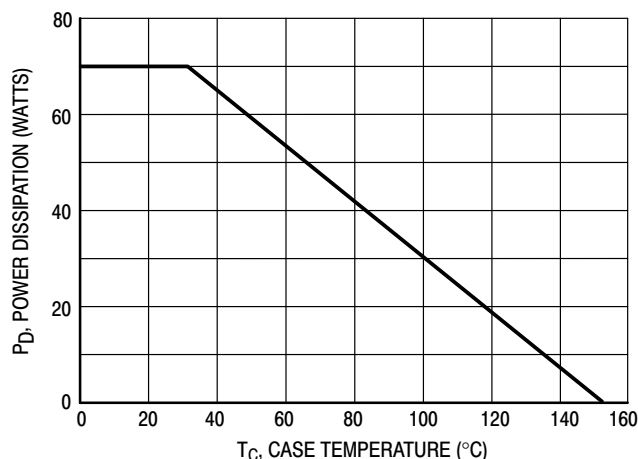
BDX3xy = Device Code  
x = 3 or 4  
y = B or C  
A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb–Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## BDX33B, BDX33C (NPN) BDX34B, BDX34C (PNP)



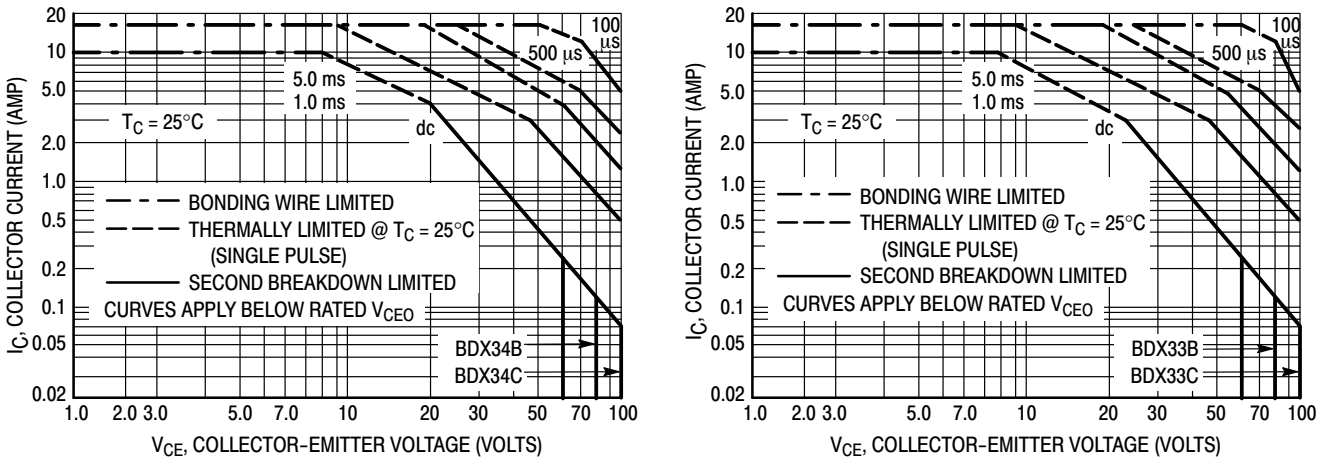
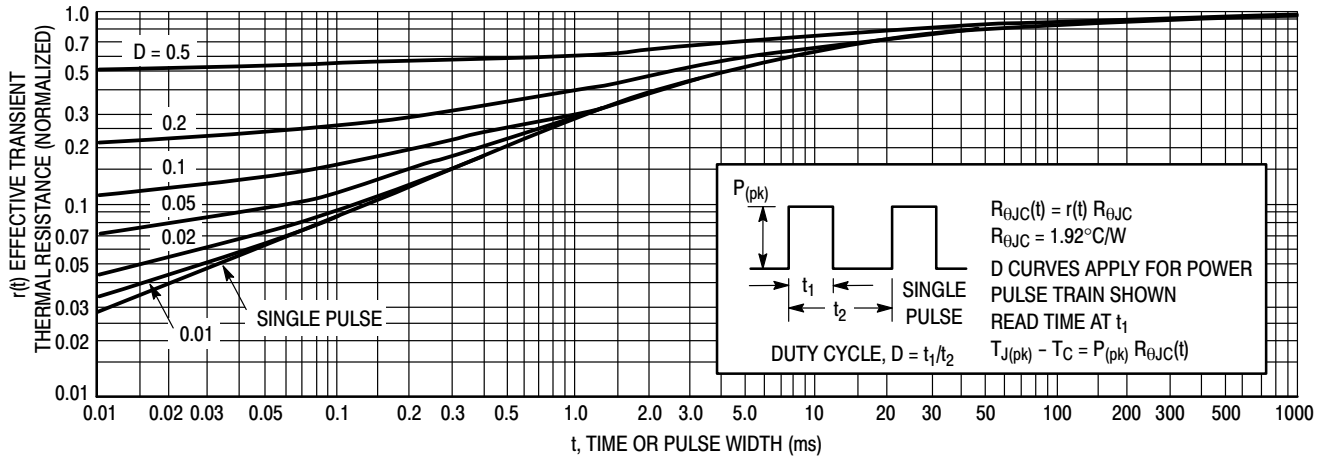
**Figure 1. Power Derating**

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
<b>OFF CHARACTERISTICS</b>					
Collector-Emitter Sustaining Voltage (Note 1) ( $I_C = 100\text{ mAdc}$ , $I_B = 0$ )	BDX33B/BDX34B BDX33C/BDX34C	$V_{CEO(sus)}$	80 100	- -	Vdc
Collector-Emitter Sustaining Voltage (Note 1) ( $I_C = 100\text{ mAdc}$ , $I_B = 0$ , $R_{BE} = 100$ )	BDX33B/BDX34B BDX33C/BDX33C	$V_{CER(sus)}$	80 100	- -	Vdc
Collector-Emitter Sustaining Voltage (Note 1) ( $I_C = 100\text{ mAdc}$ , $I_B = 0$ , $V_{BE} = 1.5\text{ Vdc}$ )	BDX33B/BDX34B BDX33C/BDX34C	$V_{CEX(sus)}$	80 100	- -	Vdc
Collector Cutoff Current ( $V_{CE} = 1/2$ rated $V_{CEO}$ , $I_B = 0$ )	$T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	$I_{CEO}$	- -	0.5 10	mAdc
Collector Cutoff Current ( $V_{CB} =$ rated $V_{CBO}$ , $I_E = 0$ )	$T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	$I_{CBO}$	- -	1.0 5.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )		$I_{EBO}$	-	10	mAdc
<b>ON CHARACTERISTICS</b>					
DC Current Gain (Note 1) ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ )	BDX33B, 33C/34B, 34C	$h_{FE}$	750	-	-
Collector-Emitter Saturation Voltage ( $I_C = 3.0\text{ Adc}$ , $I_B = 6.0\text{ mAdc}$ )	BDX33B, 33C/34B, 34C	$V_{CE(sat)}$	-	2.5	Vdc
Base-Emitter On Voltage ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ )	BDX33B, 33C/34B, 34C	$V_{BE(on)}$	-	2.5	Vdc
Diode Forward Voltage ( $I_C = 8.0\text{ Adc}$ )		$V_F$	-	4.0	Vdc

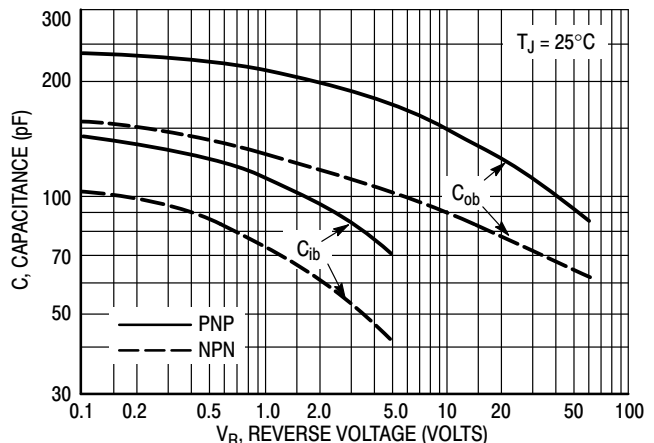
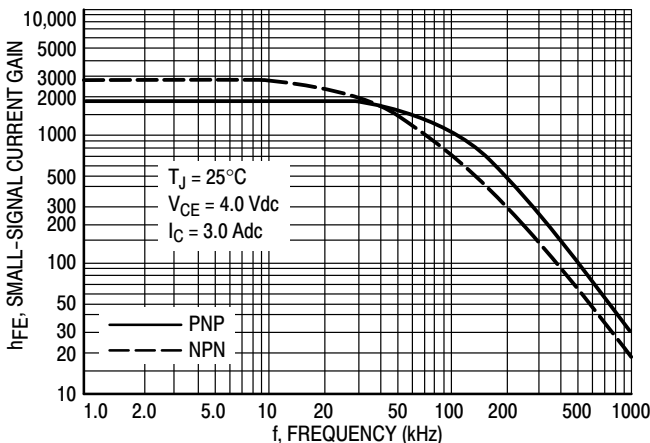
1. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .
2. Pulse Test non repetitive: Pulse Width = 0.25 seconds.

# BDX33B, BDX33C (NPN) BDX34B, BDX34C (PNP)



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of Figure 3 is based on  $T_{J(pk)}$

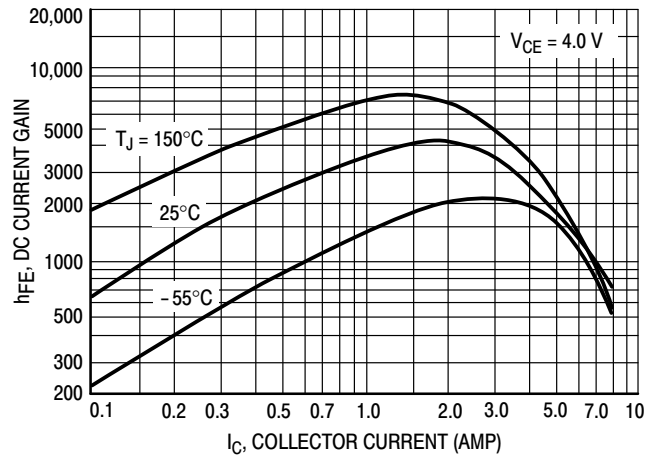
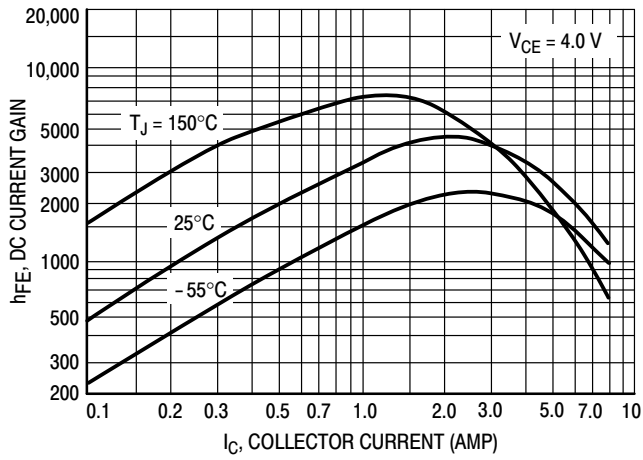
=  $150^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} = 150^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



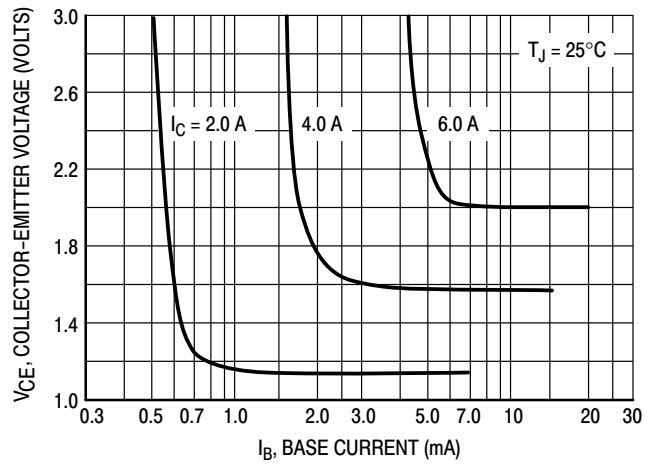
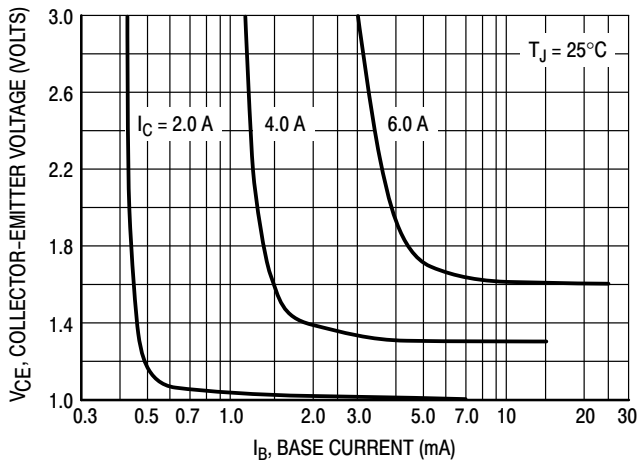
# BDX33B, BDX33C (NPN) BDX34B, BDX34C (PNP)

**NPN**  
**BDX33B, 33C**

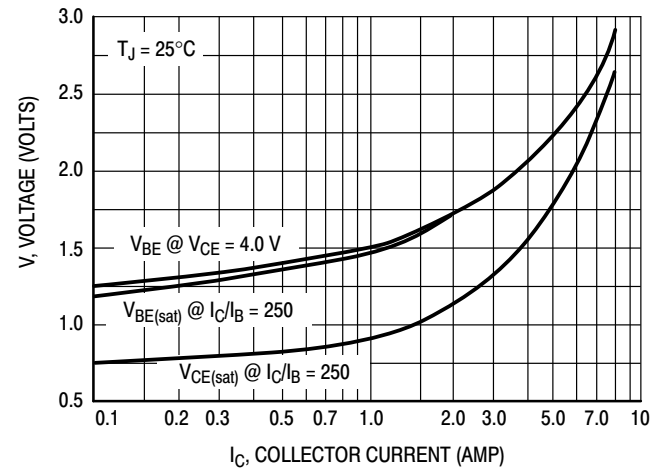
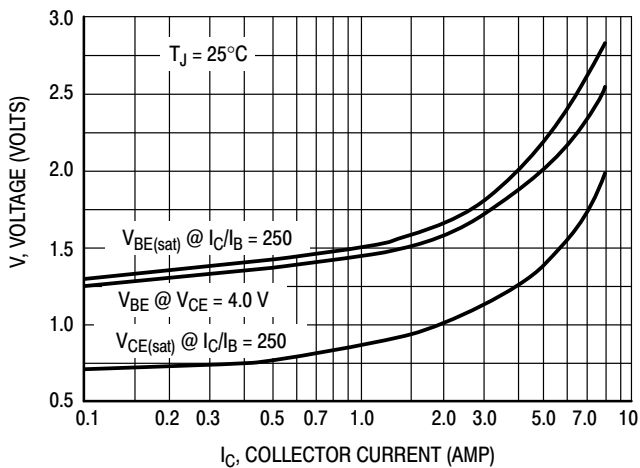
**PNP**  
**BDX34B, 34C**



**Figure 5. DC Current Gain**



**Figure 6. Collector Saturation Region**



**Figure 7. "On" Voltages**

## BDX33B, BDX33C (NPN) BDX34B, BDX34C (PNP)

### ORDERING INFORMATION

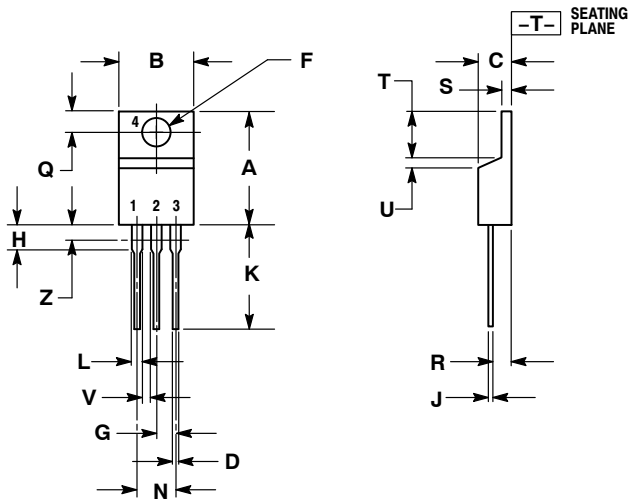
Device	Package	Shipping†
BDX33B	TO-220	50 Units / Rail
BDX33BG	TO-220 (Pb-Free)	
BDX33C	TO-220	50 Units / Rail
BDX33CG	TO-220 (Pb-Free)	
BDX34B	TO-220	50 Units / Rail
BDX34BG	TO-220 (Pb-Free)	
BDX34C	TO-220	50 Units / Rail
BDX34CG	TO-220 (Pb-Free)	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# BDX33B, BDX33C (NPN) BDX34B, BDX34C (PNP)

## PACKAGE DIMENSIONS

### TO-220 CASE 221A-09 ISSUE AG



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

#### STYLE 1:

- PIN 1. BASE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

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- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
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- Работу по проектам и поставку образцов.
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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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